

# KSA1015GRBU

Request a Quote

### **KSA1015GRBU** Information

	Part Number	KSA1015GRBU	
www.ibgisgner.com	Manufacturer	Fairchild/ON Semiconductor	
	Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single	
	Description	TRANS PNP 50V 0.15A TO-92	
l'and and and and and and and and and and	Package	TO-226-3, TO-92-3 (TO-226AA)	
		For the pricing/inventory/lead time, please contact	
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## **KSA1015GRBU** Specifications

Manufacturer Part NumberKSA1015GRBUManufacturerFairchild/ON SemiconductorCategoryDiscrete Semiconductor ProductsTransistor Selipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypePNPCurrent - Collector (Ic) (Max)150mAVoltage - Collector Emitter Breakdown (Max)50VVce Saturation (Max) @ Ib, Ic300mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce200 @ 2mA, 6VPower - Max400mWFrequency - TransitionS0WHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO -226.3, TO-92.3 (TO-226AA)	
CategoryDiscrete Semiconductor ProductsCategoryTransistors - Bipolar (BJT) - SinglePackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypePNPCurrent - Collector (Ic) (Max)150mAVoltage - Collector Emitter Breakdown (Max)50VVce Saturation (Max) @ Ib, Ic300mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce200 @ 2mA, 6VPower - Max400mWFrequency - Transition80MHzOprating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
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PackageTO-226-3, TO-92-3 (TO-226AA)Series-Transistor TypePNPCurrent - Collector (Lc) (Max)150mAVoltage - Collector Emitter Breakdown (Max)50VVce Saturation (Max) @ Ib, Ic300mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce200 @ 2mA, 6VPower - Max400mWFrequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
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Transistor TypePNPCurrent - Collector (Ic) (Max)150mAVoltage - Collector Emitter Breakdown (Max)50VVcc Saturation (Max) @ Ib, Ic300mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce200 @ 2mA, 6VPower - Max400mWFrequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTo-226-3, TO-92-3 (TO-226AA)	
Current - Collector (Ic) (Max)150mAVoltage - Collector Emitter Breakdown (Max)50VVce Saturation (Max) @ Ib, Ic300mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce200 @ 2mA, 6VPower - Max400mWFrequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
Voltage - Collector Emitter Breakdown (Max)50VVce Saturation (Max) @ Ib, Ic300mV @ 10mA, 100mACurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce200 @ 2mA, 6VPower - Max400mWFrequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-226AA)	
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DC Current Gain (hFE) (Min) @ Ic, Vce200 @ 2mA, 6VPower - Max400mWFrequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
Power - Max400mWFrequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-226AA)	
Frequency - Transition80MHzOperating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
Operating Temperature150°C (TJ)Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
Mounting TypeThrough HolePackage / CaseTO-226-3, TO-92-3 (TO-226AA)	
Package / Case TO-226-3, TO-92-3 (TO-226AA)	
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Supplier Device Package TO-92-3	
Report	errors?

#### **KSA1015GRBU** Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### **KSA1015GRBU** Payment Methods



## KSA1015GRBU Shipping Methods



If you have any question about KSA1015GRBU, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com